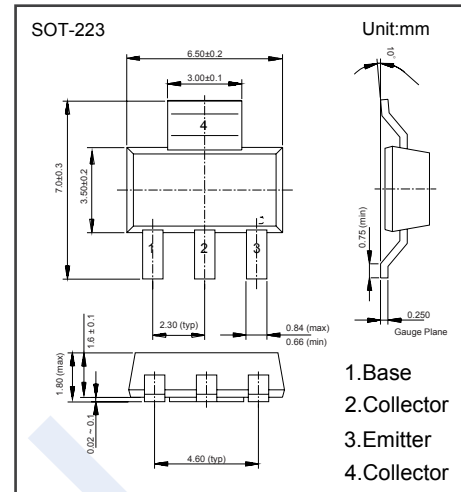


NPN Transistors

FZT1051A (KZT1051A)

■ Features

- Collector Current Capability $I_C=5A$
- Collector Emitter Voltage $V_{CEO}=40V$
- Low Saturation Voltage



■ Absolute Maximum Ratings $T_a = 25^\circ C$

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CBO}	150	V
Collector - Emitter Voltage	V_{CEO}	40	
Emitter - Base Voltage	V_{EBO}	5	
Collector Current - Continuous	I_C	5	A
Collector Current - Pulse	I_{CP}	10	
Base Current	I_B	500	mA
Collector Power Dissipation	P_C	2.5	W
Junction Temperature	T_J	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55 to 150	

NPN Transistors

FZT1051A (KZT1051A)

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	V _{CBO}	I _C = 100 μA, I _E = 0	150			V
Collector- emitter breakdown voltage	V _{CES}	I _C = 100 μA, I _B = 0	150			
Collector- emitter breakdown voltage	V _{CEO}	I _C = 10 mA, I _B = 0	40			
Collector- emitter breakdown voltage	V _{CEV}	I _C = 100 μA, V _{EB} = 1V	150			
Emitter - base breakdown voltage	V _{EBO}	I _E = 100 μA, I _C = 0	5			
Collector-base cut-off current	I _{CBO}	V _{CB} = 120 V , I _E = 0			10	nA
Collector- emitter cut-off current	I _{CES}	V _{CES} = 120 V , I _E = 0			10	
Emitter cut-off current	I _{EBO}	V _{EB} = 4V , I _C =0			10	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =200 mA, I _B =10mA			25	mV
		I _C =1 A, I _B =10mA			120	
		I _C =2 A, I _B =20mA			180	
		I _C =5 A, I _B =100mA			340	
Base - emitter saturation voltage	V _{BE(sat)}	I _C =5 A, I _B =100mA			1100	
Base - emitter turn-on voltage	V _{BE(on)}	V _{CE} = 2V, I _C = 5 A			1000	
DC current gain	h _{FE}	V _{CE} = 2V, I _C = 10mA	290			
		V _{CE} = 2V, I _C = 1A	270		1200	
		V _{CE} = 2V, I _C = 5A	130			
		V _{CE} = 2V, I _C = 10A	40			
Turn-on time	t _{on}	I _C =3A, I _B =30mA, V _{CC} =10V		220		ns
Turn-off time	t _{off}			540		
Collector output capacitance	C _{ob}	V _{CB} = 10V, f=1MHz			40	pF
Transition frequency	f _T	V _{CE} = 10V, I _C = 50mA, f=100MHz		155		MHz

Note. Pulse width=300us. Duty cycle ≤ 2%

■ Marking

Marking	1051A K****
---------	----------------

NPN Transistors

FZT1051A (KZT1051A)

■ Typical Characteristics

